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## Power Matters™

Home ▶ JANTXV2N6438 (#23957)

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**Products** 

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Overview	Diagrams
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Electrical Rating	Symbol	Min	Тур	Max	Unit
DC Current Gain	HFE	30.00		120.00	
Turn Off Time (nS)	t <sub>off</sub>			1250.00	ns

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Collector Current (dc)	I <sub>C</sub>			25.00	Α
Collector-Emitter Voltage (Base Open)	V <sub>CEO</sub>			120.00	V
Junction Temperature (°C)	T <sub>J</sub>			200.00	°C

This part can be found in the following product categories:

- Non-Radiation Hardened Devices ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ PNP Transistor
- ▶ Discretes ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ PNP Transistor

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